

SUPPORTING INFORMATION

High-efficiency self-powered perovskite photodetector with electron-enhancing SnO₂/WS₂ double electron transport layer

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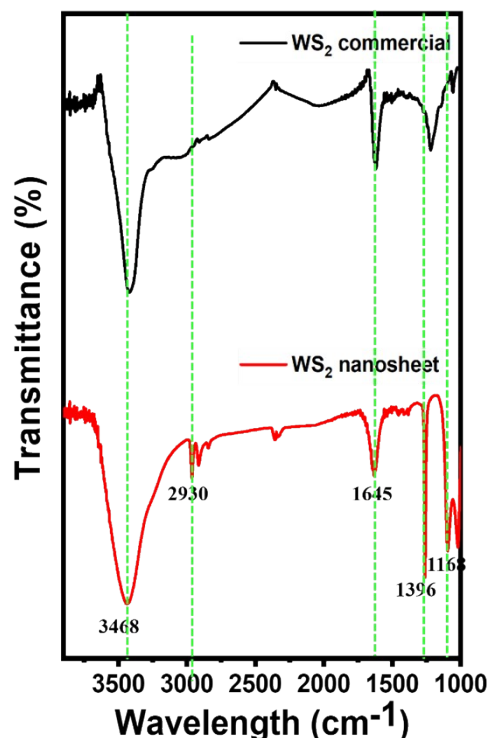


Fig. S1. FT-IR of WS₂ commercial and WS₂ nanosheet

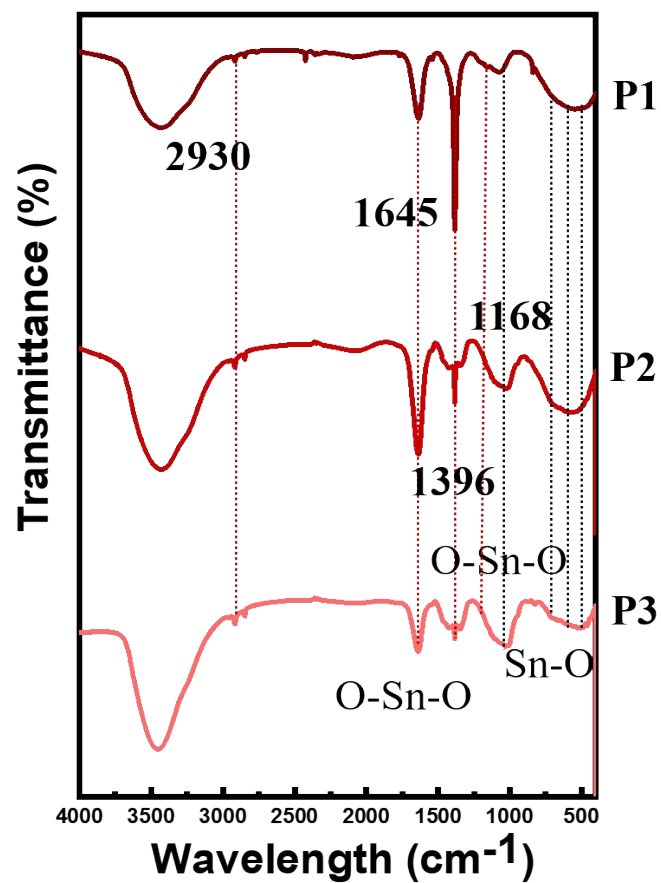


Fig. S2. FTIR of SnO₂-WS₂ at P1, P2, and P3 conditions

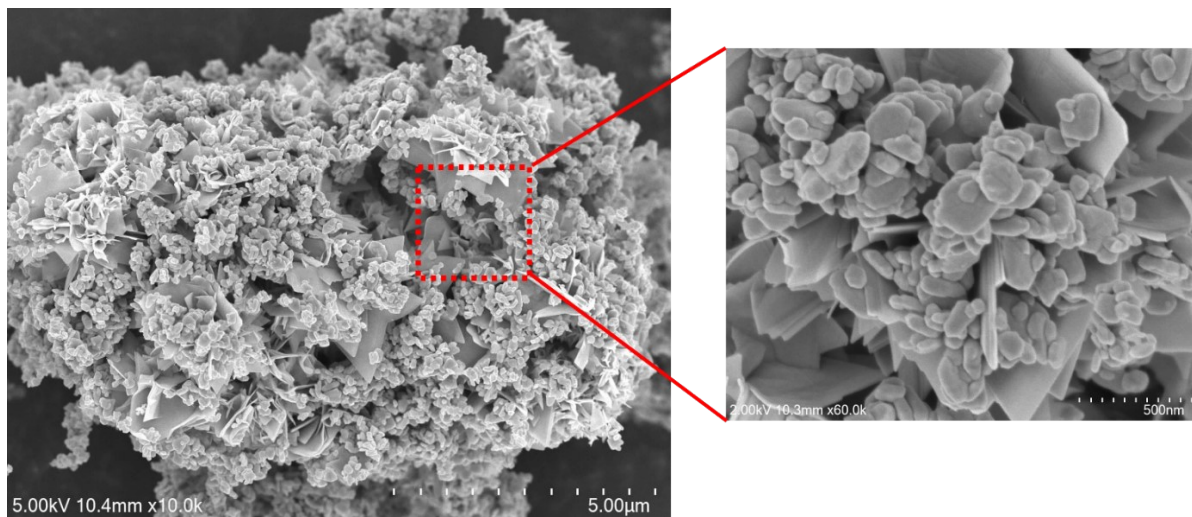


Fig. S3. SEM image of WS₂ commercial

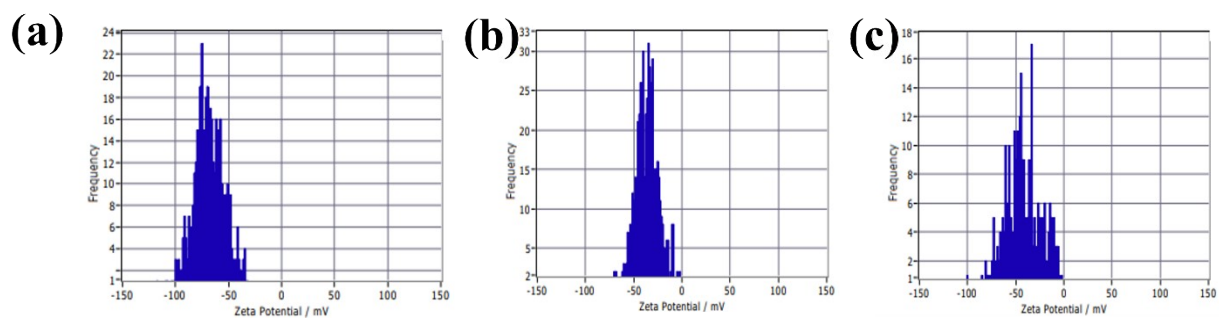


Fig. S4. Zeta potential of (a) SnO₂, (b) WS₂, (c)SnO₂-WS₂

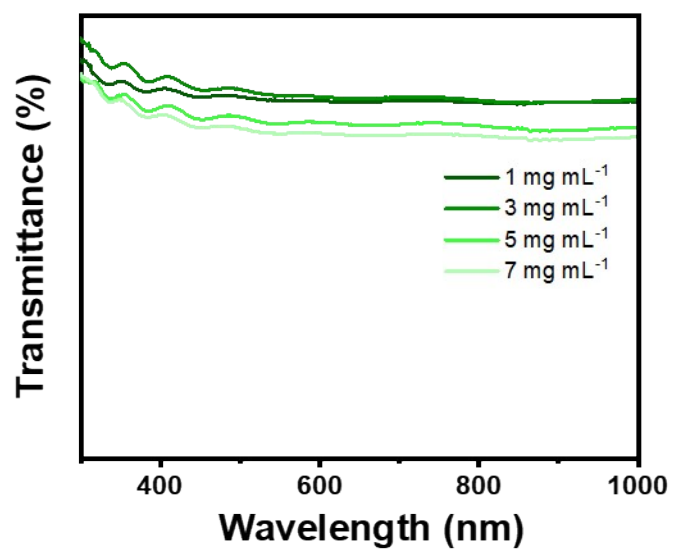


Fig. S5. Transmittance of WS₂ at different concentrations.

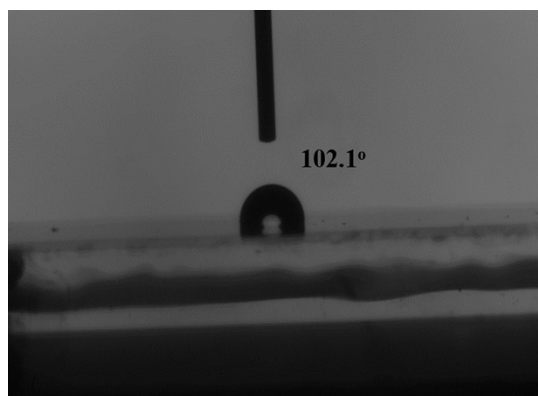


Fig. S6. Contact angel measurment of WS₂

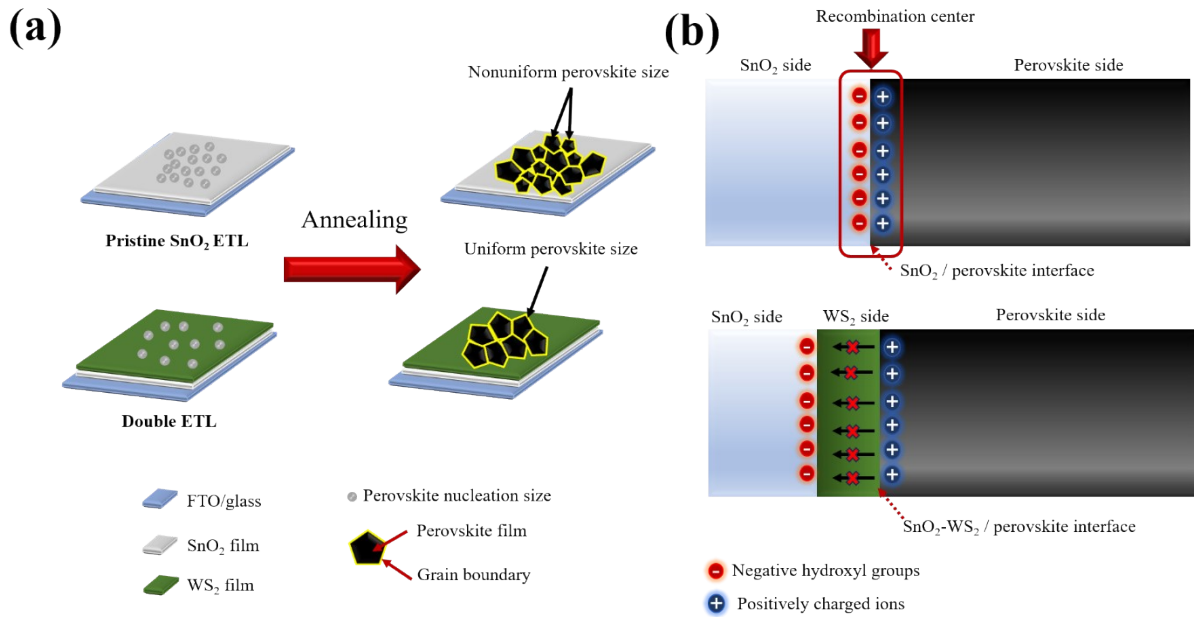


Fig. S7. (a) Schematic illustration of the nucleation of perovskite on pristine SnO_2 and SnO_2/WS_2 ETL, (b) Schematic illustration of the formation of recombination center between negative hydroxyl groups from SnO_2 side and positively charge ions from perovskite in the structure with and without the presence of WS_2

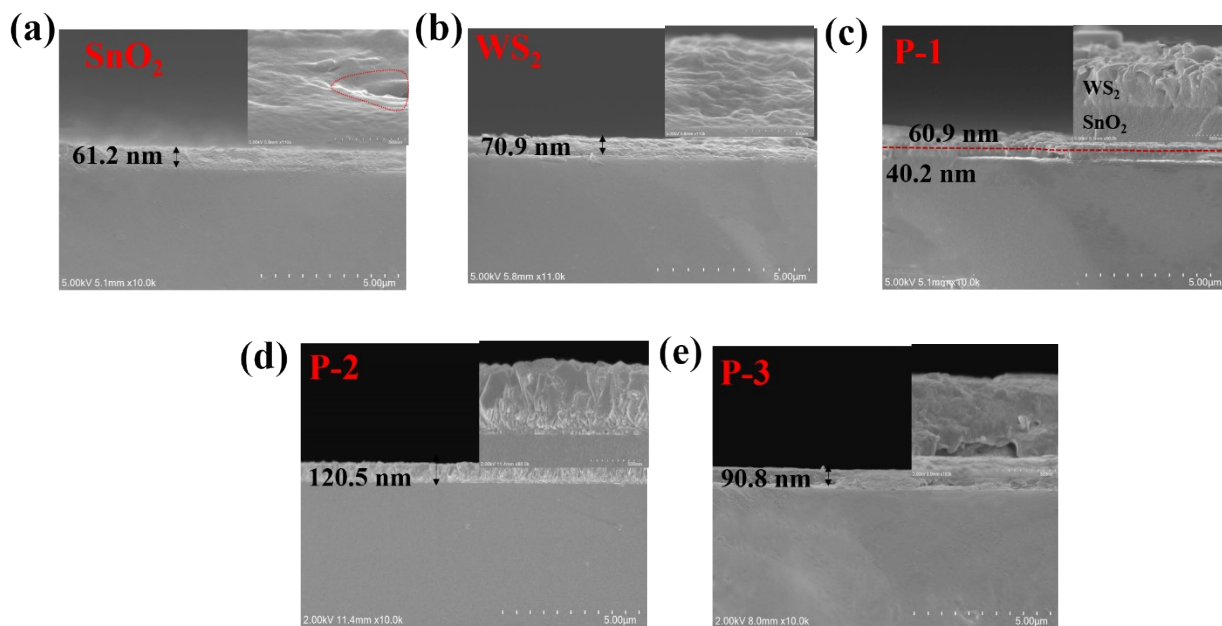


Fig. S8. (a) Cross-section SEM image of (a) FTO/SnO₂, (b) FTO/WS₂, (c) FTO/SnO₂-WS₂ (P1), (d) FTO/SnO₂-WS₂ (P2), (e) FTO/SnO₂-WS₂ (P3)

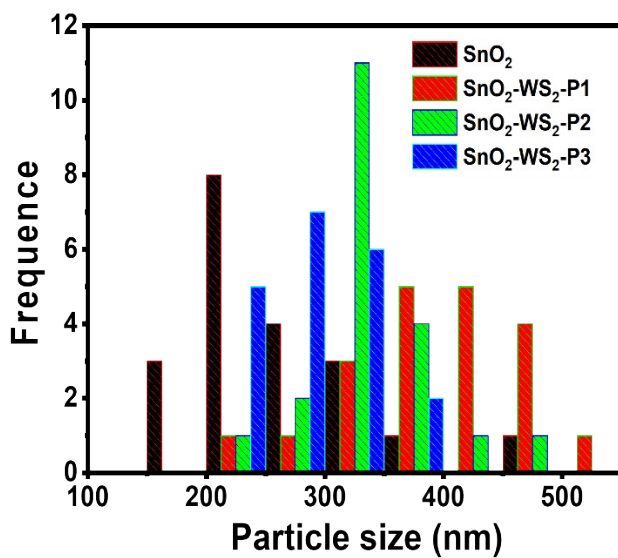


Fig. S9. Particle size distribution on SnO₂, SnO₂-WS₂ (P1), SnO₂-WS₂ (P2), and SnO₂-WS₂ (P3)

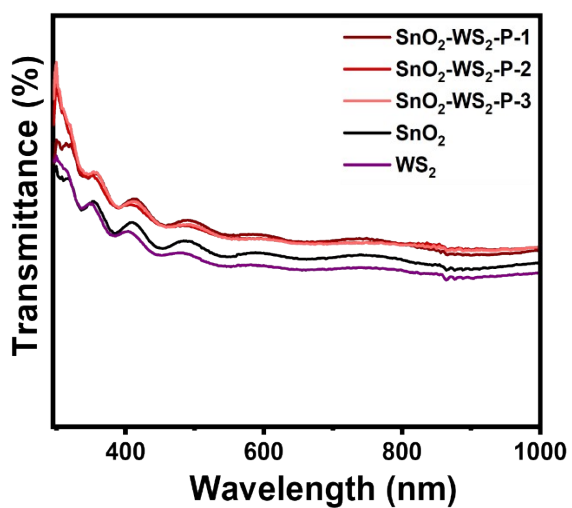


Fig. S10. Transmittance of SnO₂, WS₂, SnO₂-WS₂ (P1), SnO₂-WS₂ (P2), and SnO₂-WS₂ (P3)

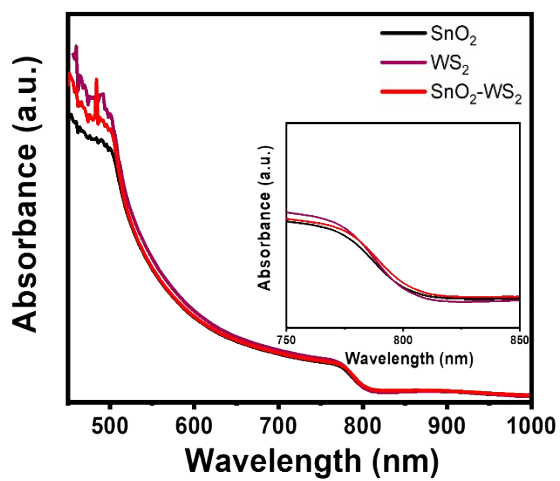


Fig. S11. Absorbance of perovskite on different ETLs

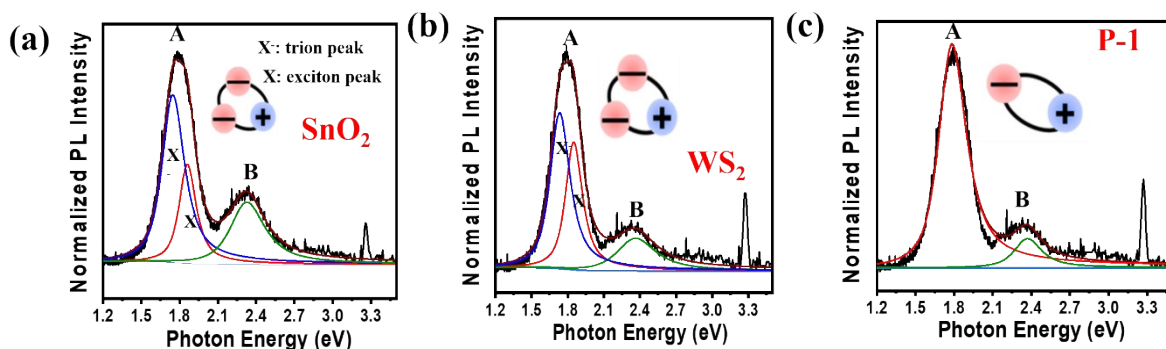


Fig. S12. Analysis of the PL spectral shapes for (a) SnO_2 , (b) WS_2 , and (c) as-prepared SnO_2 - WS_2 -P1. The A peaks in the PL spectra were reproduced by assuming two peaks with Lorentzian functions, corresponding to the trion (X^-) and the exciton (X) peaks.

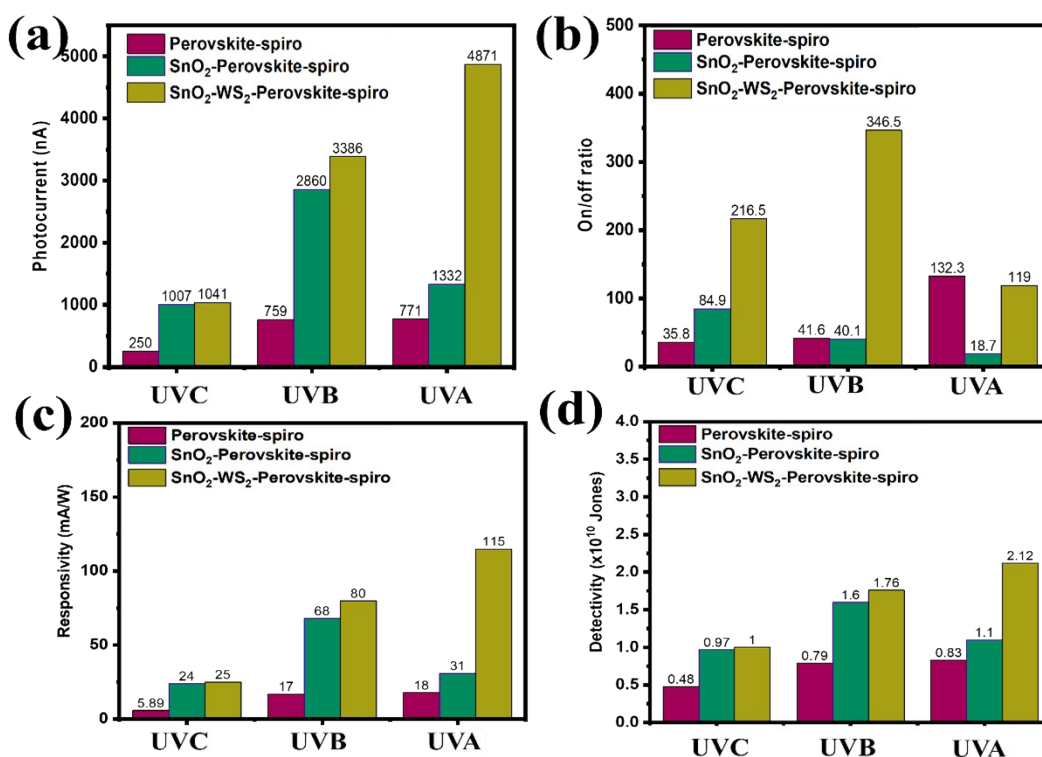


Fig. S13. The performance of different PD devices with (a) Time-domain response (b) on/off ratio, (c) responsivity, and (d) detectivity

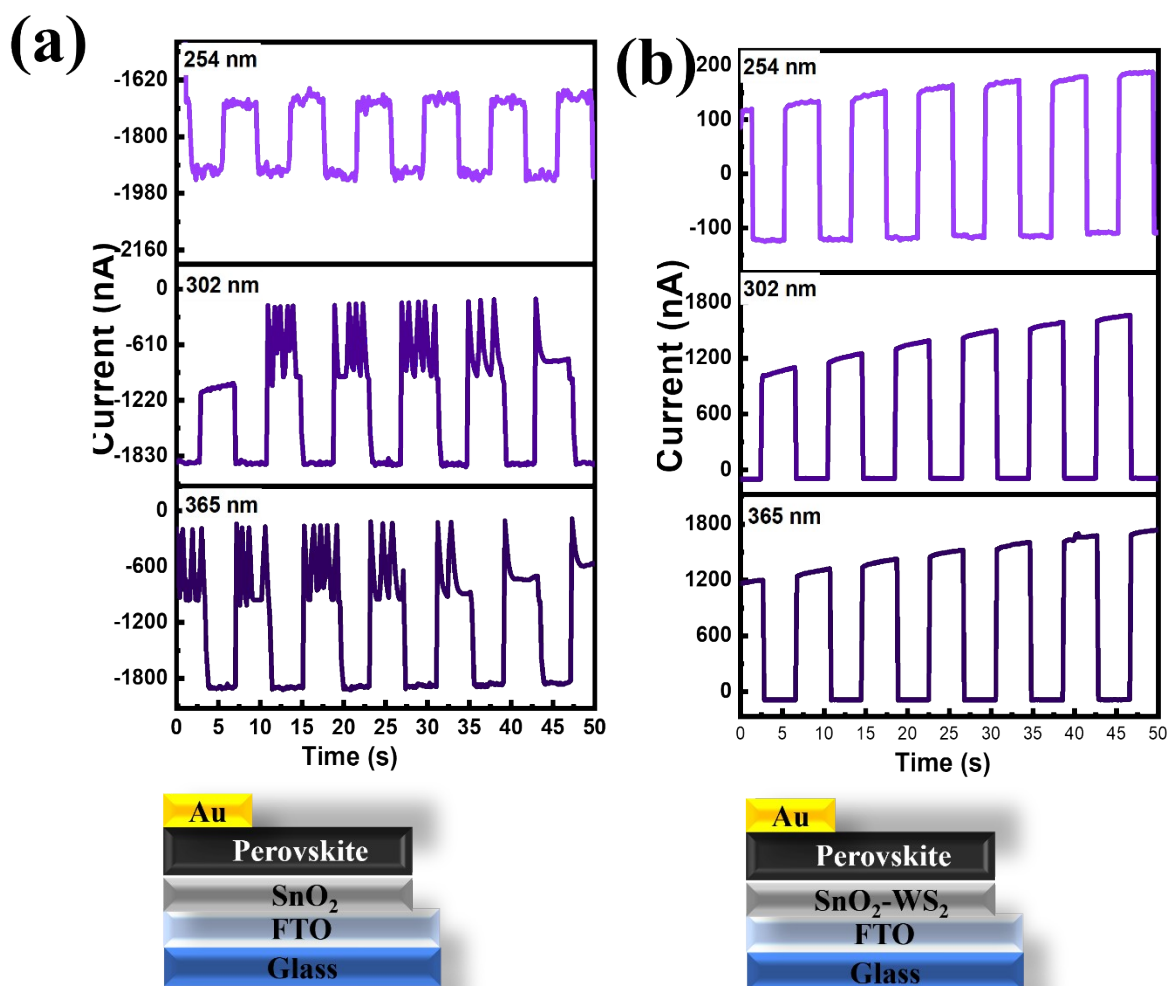


Fig. S14. Time-domain response of different PD device without HTL

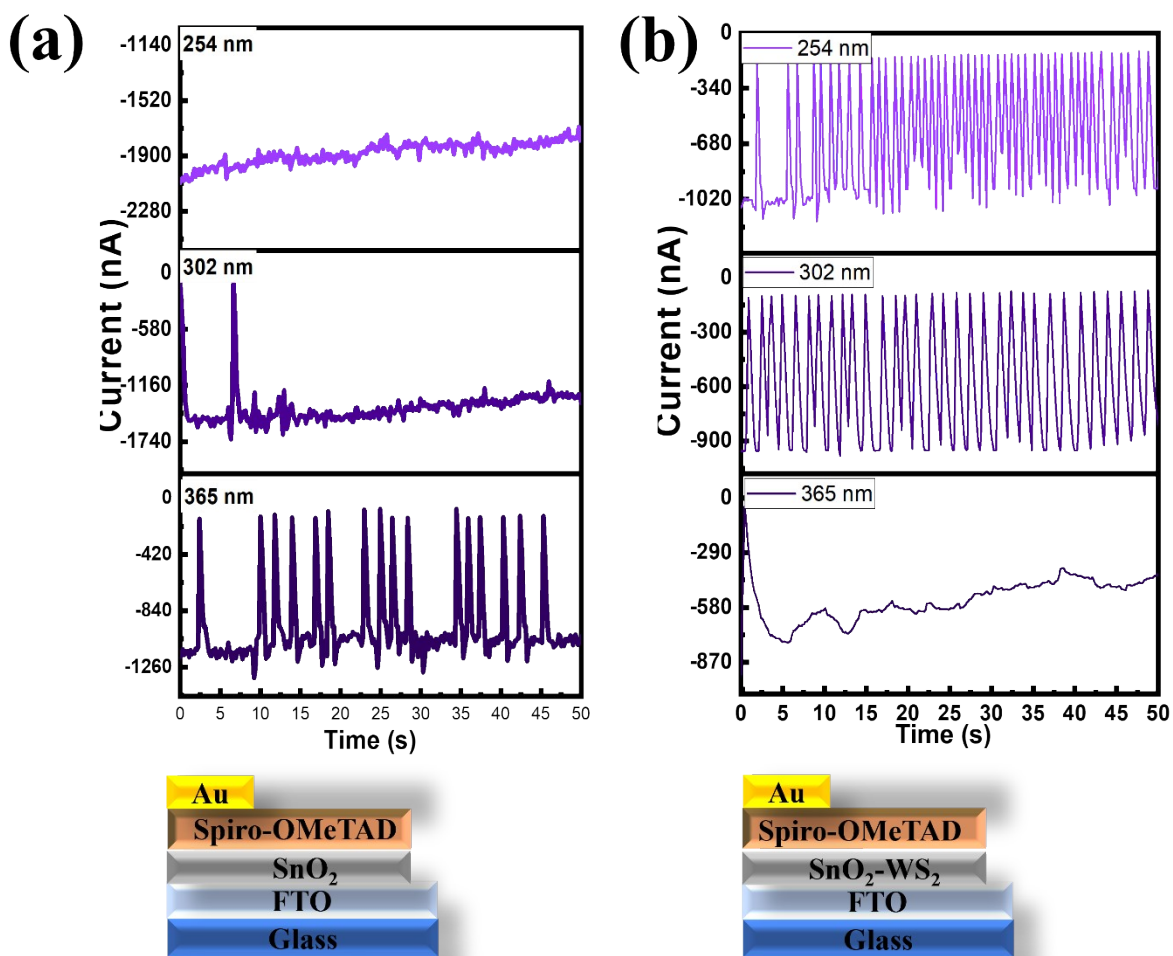


Fig. S15. Time-domain response of different PD device without photoactive

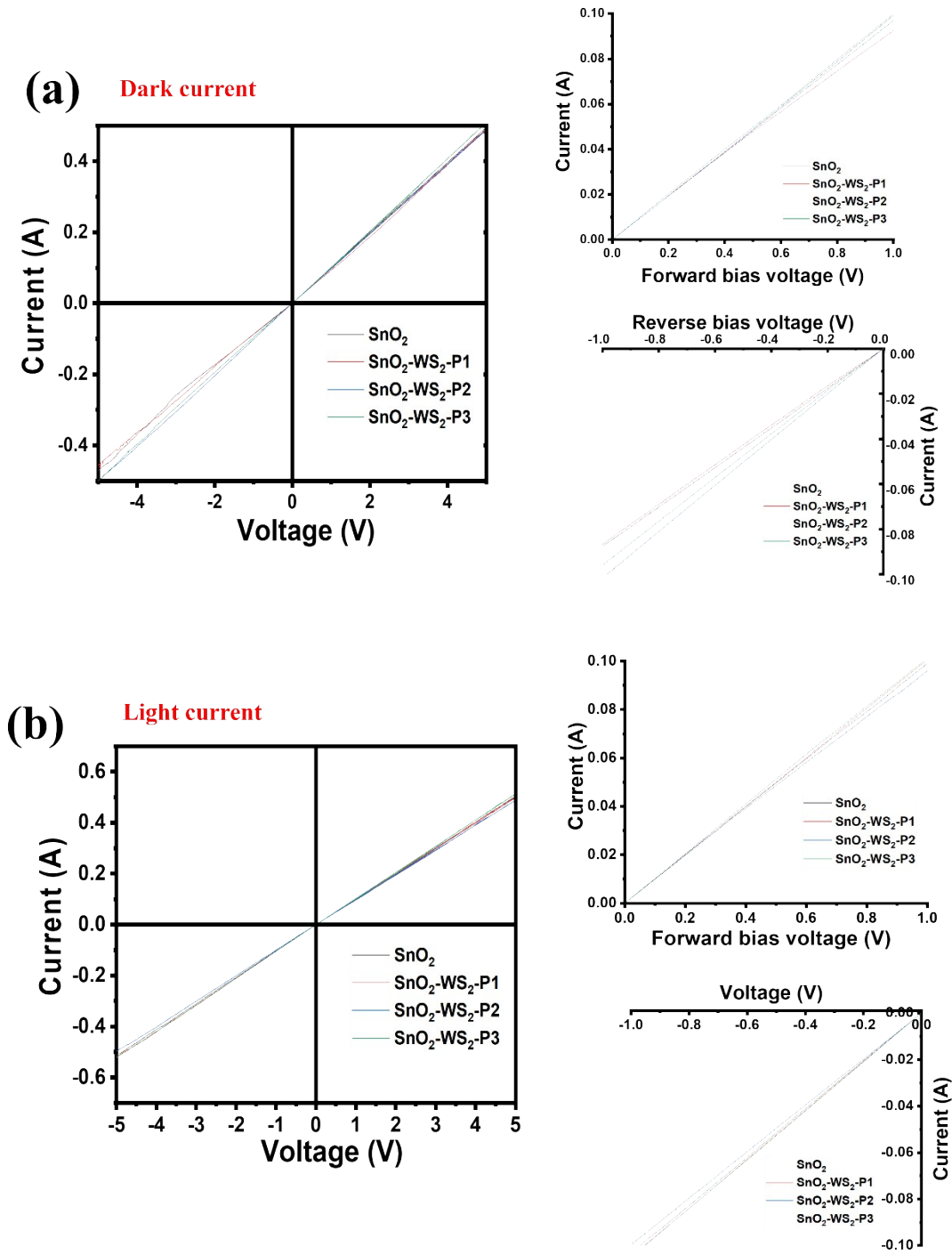


Fig. S16. I-V curves of different ETL at (a) a dark environment and (b) under 254 nm irradiation

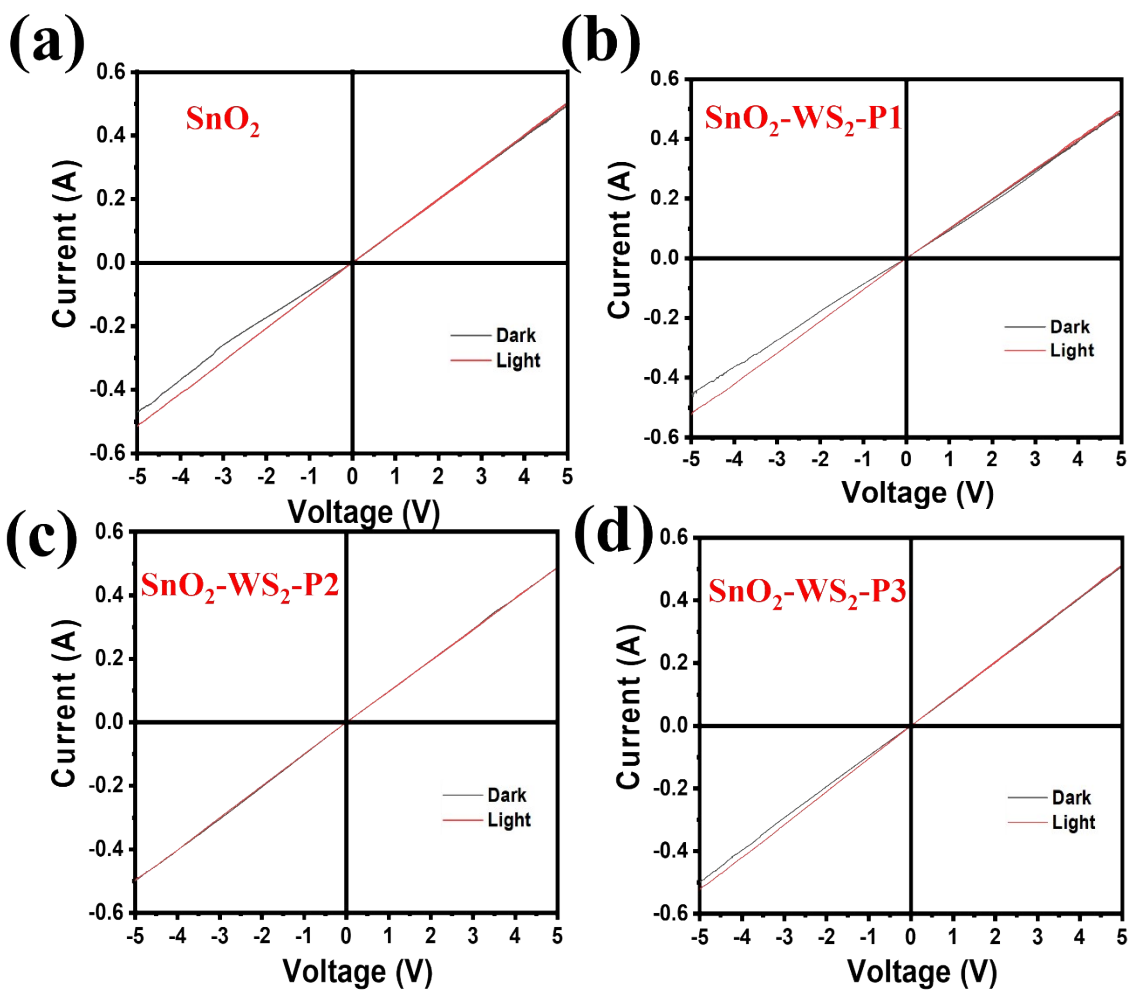
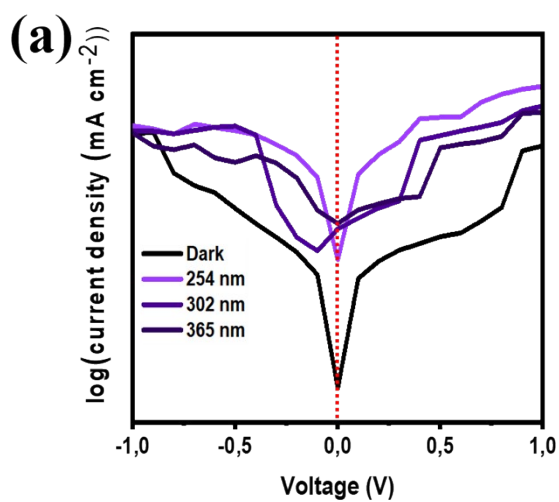
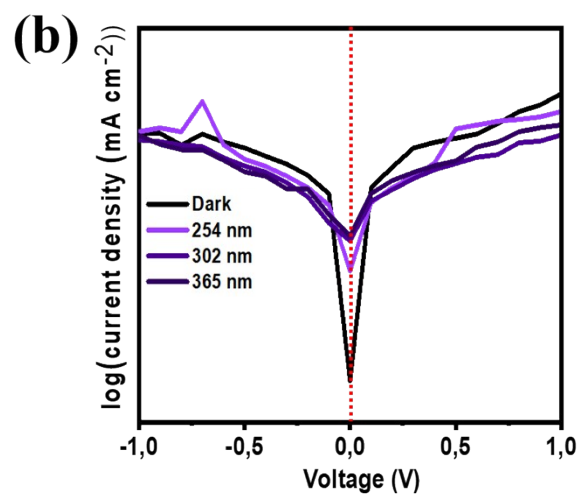


Fig. S17. I-V curves of PD devices at different ETL at (a) a dark environment and (b) under 254 nm irradiation



FTO/SnO₂-WS₂/Perovskite/spiro-OMeTAD/Au



FTO/SnO₂/Perovskite/spiro-OMeTAD/Au

Fig. S18. J-V curves of PD devices at different ETL in a dark environment and under 254 nm, 302 nm, and 365 nm radiation.

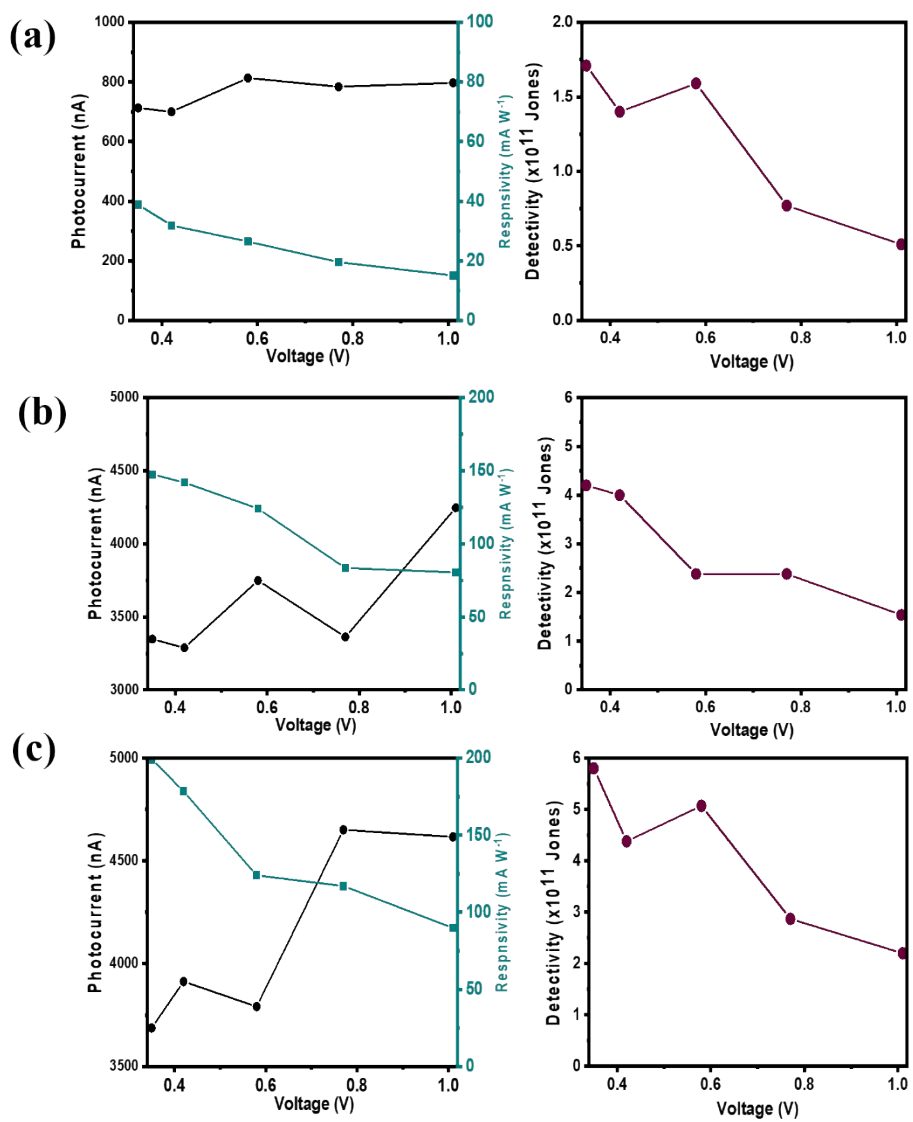


Fig. S19. The performance of different PD devices with photocurrent, responsivity, and detectivity of (a) UVC, (b) UVB, and (c) UVA regions.

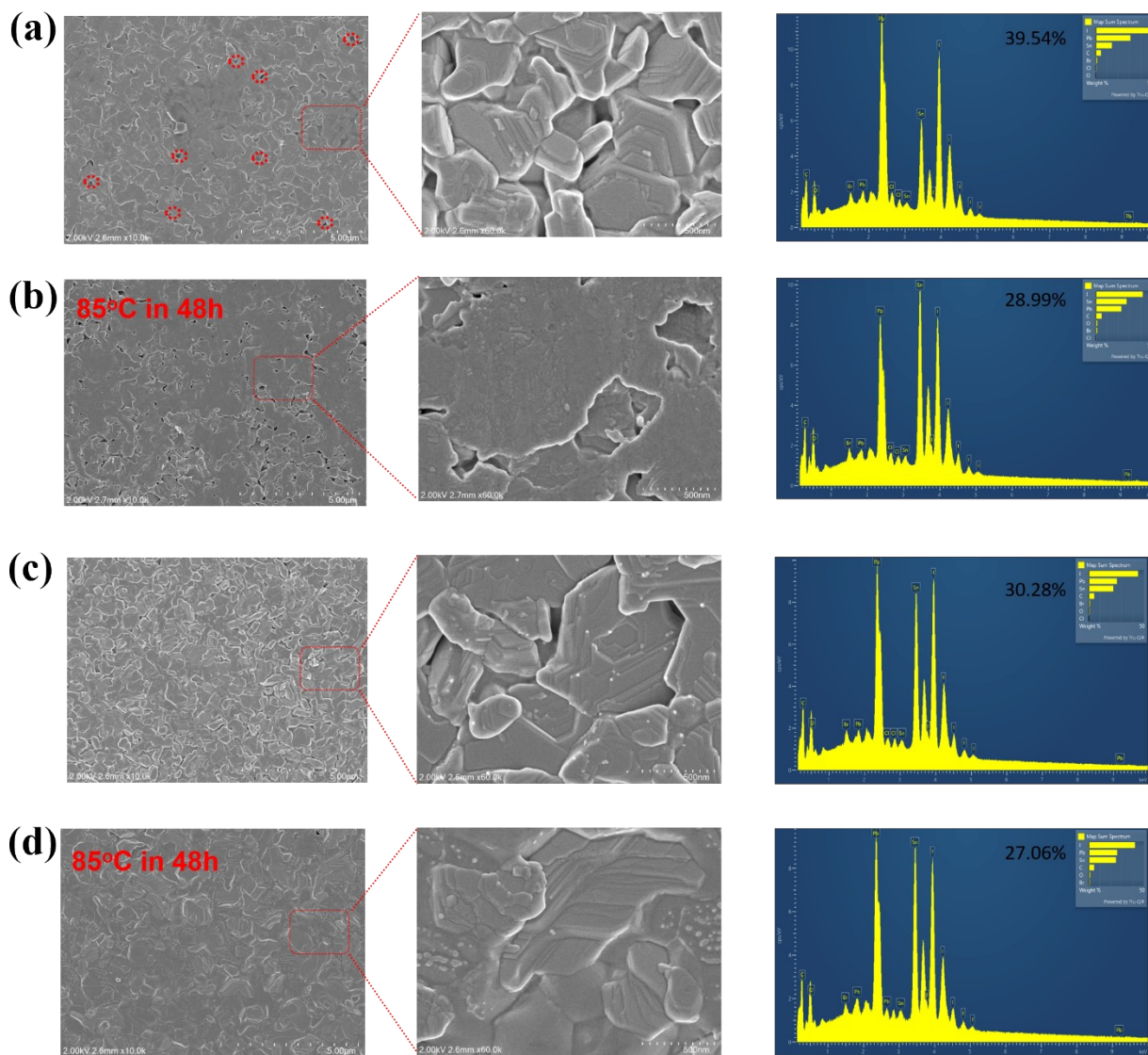


Fig. S20. SEM image and EDX analysis of perovskite coating on (a) SnO₂ at normal condition, (b) SnO₂ at 85°C in 48h, (c) SnO₂-WS₂ at normal condition, and (d) SnO₂-WS₂ at 85°C in 48h.